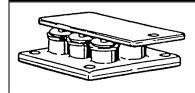


High Power Transient Voltage Suppressor and Zener

DESCRIPTION

This high power Transient Voltage Suppressor and Zener is designed for applications requiring protection of voltage-sensitive electronic devices that may be damaged by high power or high energy voltage transients including lightning per IEC61000-4-5 and classes 1-4 with various source impedances described herein. Individual cells are matched to ensure current-sharing under high current pulse conditions and for continuous operation as a Zener when required.

APPEARANCE



IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

FEATURES

- Peak surge power capacity given from 0.1 ms to 10 seconds.
- · Low clamping factor
- Negligible power loss
- Small size and weight for 350 W dc rating
- Low thermal resistance junction to base plate
- Working Standoff Voltages 14 to 165 Volts
- Following variations are also available:
 - Non-Standard Voltages
 - Higher Power Capacity
 - Other Package Configurations

MAXIMUM RATINGS

- Transient Peak Pulse Power: 40 kW at 0.1 ms and 8 kW at 1.0 ms (sq. wave) or 12 kW @ 10/1000 us
- DC Power Dissipation: 350 Watts @ T_c = 25°C (Derate 2.33 W°C above 25°C)
- Operating junction & storage temperature range: -65°C to +175°C.

APPLICATIONS / BENEFITS

- High Power Voltage Regulation
- High Power Transient Voltage Protection from Lightning per IEC61000-4-5 for class 1,2,3,4, and 5 with source impedance of 42 Ohms
- High Power Transient Voltage Protection from Lightning per IEC61000-4-5 for class 1,2,3, and 4 with source impedance of 12 Ohms for MPZ5-16 and MPZ5-32 device types
- High Power Transient Voltage Protection from Lightning per IEC61000-4-5 for class 2 and 3 with source impedance of 2 Ohms for MPZ5-16 and MPZ-32 as well as class 4 for MPZ5-16

MECHANICAL AND PACKAGING

- Robust copper heat-sink mounting plates and cells
- Finish: Nickel-Solder Plated
- Polarity: Anode-to-Case is standard. Cathode-to-Case available upon request.
- Weight: 61 grams (approximate)

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_F = 1.5 \text{ V max } @ 10 \text{ A for all types}$)

| | Rated S | standoff | Maximum Device | | | Maximu | m Zener | | Typical |
|-----------|----------|----------|--|---------------------|---------------------|------------------------|--------------|-------------------|-------------------|
| | Volta | age | Clamping Factor | Minin | num | Volt | tage | Maximum | Capacitance |
| | (Note 1) | | 0= \/ @ (nules) | Zener Voltage | | Pulse Width = 1.0 ms | | Standby Current | C (typ) |
| | | | $CF = \frac{V_Z @ I_Z(pulse)}{Vz @ Izt}$ | | | | | ĺ _D | @ V _{WM} |
| | V_{WM} | V_{WM} | V = 0 . = v | V _Z (min |) @ I _{ZT} | V _Z (max) @ | 2 Iz (pulse) | @ V _{wm} | μF |
| Type | Vdc | Vrms | (Note 2) | Vdc | Adc | Vdc | Adc | μAdc | |
| MPZ5-16A | 14 | 10 | 1.25 | 16 | 0.4 | 24 | 200 | 50 | 0.025 |
| MPZ5-16B | 14 | 10 | 1.25 | 16 | 0.4 | 20 | 200 | 50 | 0.025 |
| MPZ5-32A | 28 | 20 | 1.25 | 32 | 0.2 | 50 | 100 | 50 | 0.011 |
| MPZ5-32B | 28 | 20 | 1.25 | 32 | 0.2 | 45 | 100 | 50 | 0.011 |
| MPZ5-32C | 28 | 20 | 1.25 | 32 | 0.2 | 40 | 100 | 50 | 0.011 |
| MPZ5-180A | 165 | 117 | 1.14 | 180 | 0.03 | 250 | V 20 | 50 | 0.0012 |
| MPZ5-180B | 165 | 117 | 1.14 | 180 | 0.03 | 225 | 20 | 50 | 0.0012 |
| MPZ5-180C | 165 | 117 | 1.14 | 180 | 0.03 | 205 | 20 | 50 | 0.0012 |

NOTE 1: Rated Standoff Voltage (V_{VM}) is defined as normal input voltage to device for non-operating condition. If non-sinusoidal wave or do input is present, the peak operating voltage input values for V_{VM} should be used to select device type.

NOTE 2: The maximum device clamping factor C_F is a ratio of V_Z measured at I_Z (pulse) given in the Electrical Characteristics Table divided by V_Z measured at I_{ZT} under steady state conditions. This value guarantees the sharpness of the voltage breakdown of individual devices. Figure 2 demonstrates the typical sharpness of the breakdown, and indicates the voltage regulation over a wide range of currents where the change in voltage ΔV_Z is as follows: $\Delta V_Z = V_Z \otimes I_Z$ (pulse) $-V_Z \otimes I_{ZT}$

Copyright © 2003 03-14-2003 REV 0

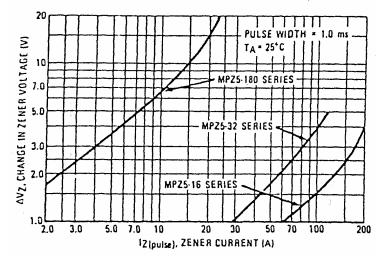


High Power Transient Voltage Suppressor and Zener

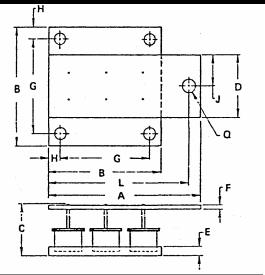
OUTLINE AND CIRCUIT

FIGURE 1 - MAXIMUM NON-REPETITIVE SURGE POWER (RECTANGULAR WAVEFORM) 100 70 50 30 P(PK). PEAK POWER (kW) 10 7.0 5.0 Tc = 35°C 3.0 2.0 1.0 0.7 0.5 0.3 0.2 0.1 ____ 0.0002 0.0005 0.005 0.001 0.002 0.01 0.02 0.05 0.1 2.0 0.5 5.0 1. TIME (SEC)

FIGURE 2 -- TYPICAL DYNAMIC ZENER VOLTAGE CHARACTERISTICS (Note 2)



PACKAGE DIMENSIONS



| | MILLIM | ETERS | INCHES | | |
|-----|--------|-------|--------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 50.29 | 51.31 | 1.980 | 2.020 | |
| В | 37.59 | 38.61 | 1.480 | 1.520 | |
| С | - | 16.51 | 1 | 0.650 | |
| D | 20.24 | 21.01 | 0.797 | 0.827 | |
| E | 2.92 | 3.43 | 0.115 | 0.135 | |
| F | 1.32 | 1.83 | 0.052 | 0.072 | |
| G | 29.97 | 30.99 | 1.180 | 1.220 | |
| Н | 3.56 | 4.06 | 0.140 | 0.160 | |
| J | 10.06 | 10.57 | 0.396 | 0.416 | |
| L | 46.74 | 47.74 | 1.840 | 1.860 | |
| Q | 3.30 | 3.81 | 0.130 | 0.150 | |